

Structure : Silicon Monolithic Integrated Circuit
Product Name : Power Driver For Compact Disc Players

Device Name : BA5826FP

Features

· 4-ch BTL driver

Use of an HSOP28 power package can achieve downsizing of the set.

• Gain can be controlled by attaching an external resistance.

· A built-in thermal shutdown circuit installed.

• A built-in 3.3V regulator installed. (External PNP Tr must be installed.)

• A built-in general operational amplifier installed.

• A built-in 2.7V reset circuit installed.

• Using an external capacitor, the reset delay time can be changed.

O ABSOLUTE MAXIMUM RATINGS (Ta=25°C)]

Parameter	Symbol	Limits	Unit
Power Supply Voltage	VCC	13.5	V
Power Dissipation	Pd	1.7 1	W
Operating Temperature Range	Topr	-35 to 85	°C
Storage Temperature Range	Tstg	-55 to 150	°C

^{*1} When mounted on the glass/epoxy board with the size: 70 mm×70 mm, the thickness: 1.6 mm, and the rate of copper foil occupancy area: 3% or less.

Over Ta=25°C, derating at the rate of 13.6mW/°C.

O OPERATING CONDITIONS

Parameter	Symbol	Limits	Unit
Power Supply Voltage	VCC	4.5 to 9	٧

This product has not been checked for the strategic materials (or service) defined in the Foreign Exchange and Foreign Trade Control Low of Japan so that a verification work is required before exporting it.

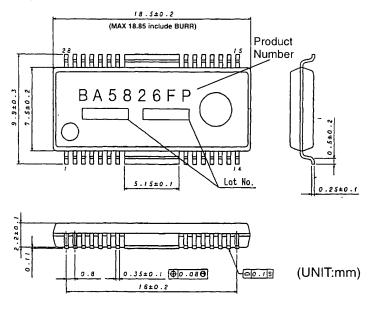
Not designed for radiation resistance.



O ELECTRIC CHARACTERISTICS (Ta=25°C, Vcc=8V, VBIAS=1.65V, R_L=8Ω, unless otherwise noted.)

Circuit Current at no signal ICC 6.0 10.0 14.0 MA No load applied	Parameter	Symbol	MIN.	TYP.	MAX	Unit	Condition
Ch1							
Output Offset Voltage VOO1 -50 - 50 MV Maximum Output Amplitude VOM1 4.35 5.0 - V VBIAS=4V Closed Circuit Voltage Gain GVC1 6.0 8.0 10.0 DB CCH2, 3, 4> VOUD 4.3 4.9 - V VBIAS=4V Cutput Offset Voltage Gain GVC2 7.0 8.0 9.0 dB Maximum Output Amplitude VOM2 4.3 4.9 - V VBIAS=4V Closed Circuit Voltage Gain GVC2 7.0 8.0 9.0 dB Closed Circuit Voltage Gain GVC2 7.0 8.0 9.0 dB Mute ON Voltage Gain GVC2 7.0 8.0 9.0 dB Mute ON Voltage VMTON - - 0.5 V Mute ON Voltage VBTHR - 0.7 1.2 V Cutput Voltage Vreg 3.13 3.3 3.47 V IL=100mA <td></td> <td colspan="3">100.000.000.000.000.000.000.000.000.000</td> <td>No load applied</td>		100.000.000.000.000.000.000.000.000.000			No load applied		
Maximum Output Amplitude VOM1 4.35 5.0 - V VBIAS=4V	191111	VOO1	-50	_	50	MV	
Closed Circuit Voltage Gain GVC1 6.0 8.0 10.0 DB	Maximum Output Amplitude			5.0	-		VBIAS=4V
CH2, 3, 4 Output Offset Voltage	Closed Circuit Voltage Gain				10.0		V5
Output Offset Voltage			0.0		1		
Maximum Output Amplitude VOM2 4.3 4.9 - V VBIAS=4V		V002	-50	_	50	mV	
Closed Circuit Voltage Gain GVC2 7.0 8.0 9.0 dB	Maximum Output Amplitude	VOM2	4.3	4.9	-	٧	VBIAS=4V
Mute OFF Voltage		GVC2		8.0	9.0	dB	
Mute ON Voltage VMTON - - 0.5 V							
Bias Drop Mute Threshold Voltage VBTHR - 0.7 1.2 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR - 0.7 V VBTHR -	Mute OFF Voltage	VMTOFF	2.0	-	-		
Voltage VBTHR - 0.7 1.2 V V		VMTON	-	-	0.5	V	
Coutput Voltage Vreg 3.13 3.3 3.47 V IL=100mA		VBTHR	-	0.7	1.2	V	
Output Voltage Vreg 3.13 3.3 3.47 V IL=100mA Output Load Regulation ΔVRL -20 0 10 mV IL=100 to 200mA Power Supply Voltage Regulation ΔVVCC -10 0 35 mV (Vcc=6 to 9V) IL=100mA VOFOP Regulation VOFOP -6 - 6 mV (Vcc=6 to 9V) IL=100mA VOFOP Regulation VOFOP -6 - 6 mV (Vcc=6 to 9V) IL=100mA VOFOP Regulation VOFOP -6 - 6 mV (Vcc=6 to 9V) IL=100mA VOFOP Regulation IBIAS - - 6 mV (Vcc=6 to 9V) IL=100mA Input Bias Current IBIAS - - 6 mV (VBIAS=4V (VBIAS=4V VBIAS=4V (VBIAS=4V (VBIAS=4V </td <td>Voltage</td> <td></td> <td></td> <td><u> </u></td> <td></td> <td></td> <td></td>	Voltage			<u> </u>			
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Regulation		ΔVHL	-20	U	10	mv	IL=100 to 200mA
Offset Voltage		ΔVVCC	-10	0	35	mV	(Vcc=6 to 9V) IL=100mA
Offset Voltage VOFOP -6 - 6 mV Input Bias Current IBIAS - - 300 nA High-level Output Voltage VOHOP 7.5 - - V VBIAS=4V Low-level Output Voltage VOLOP - - 0.3 V VBIAS=4V Output Driving Current Sink ISIN 1 - - mA VBIAS=4V Coutput Driving Current Sink ISIN 1 - - mA VBIAS=4V Reset Output> VRON - - 0.5 V When Vreg drops Reset ON Output Voltage VRON - - 0.5 V Connected to 3.3V with the resistance of 10kΩ applied. <reset output="" τ=""> IREST 16.6 23.7 30.8 μA Reset τ Threshold Voltage H VRESTH 7.7 - - V VREST=1.5V</reset>			l		l		
Input Bias Current		VOFOP	-6	-	6	mV	
High-level Output Voltage			-	-		4	
Low-level Output Voltage VOLOP - - 0.3 V VBIAS=4V			7.5	-	-	<u> </u>	VBIAS=4V
Output Driving Current Source ISOU 300 500 - μA VBIAS=4V Output Driving Current Sink ISIN 1 - - mA VBIAS=4V Reset Output Reset ON Threshold Voltage VTHR 2.56 2.7 2.84 V When Vreg drops Reset ON Output Voltage VRON - - 0.5 V Connected to 3.3V with the resistance of 10kΩ applied. <reset output="" τ=""> <reset current="" τ=""> IREST 16.6 23.7 30.8 μA Reset τ Threshold Voltage H VRESTH 7.7 - - V VREST=1.5V</reset></reset>			-	-	0.3	V	VBIAS=4V
Source Output Driving Current Sink ISIN 1 - - mA VBIAS=4V Reset Output> Reset ON Threshold Voltage VTHR 2.56 2.7 2.84 V When Vreg drops Reset ON Output Voltage VRON - - 0.5 V Connected to 3.3V with the resistance of 10kΩ applied. <reset output="" τ=""> <reset current="" τ=""> IREST 16.6 23.7 30.8 μA Reset τ Threshold Voltage H VRESTH 7.7 - V VREST=1.5V</reset></reset>	Output Driving Current	ISOU	300	500	_	11Δ	VRIAS-4V
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Reset ON Output VoltageVRON0.5VConnected to 3.3V with the resistance of 10kΩ applied. <reset output="" τ="">IREST16.623.730.8μAReset τ Threshold Voltage HVRESTH7.7-VVREST=1.5V</reset>							
Reset τ Output Voltage	Reset ON Threshold Voltage	VTHR	2.56	2.7	2.84	V	
<reset current="" τ=""> IREST 16.6 23.7 30.8 μA Reset τ Threshold Voltage H VRESTH 7.7 - V VREST=1.5V</reset>	Reset ON Output Voltage	VRON	-	-	0.5	V	
Reset τ Threshold Voltage H VRESTH 7.7 V VREST=1.5V							
Reset τ Threshold Voltage H VRESTH 7.7 V VREST=1.5V	<reset current="" τ=""></reset>	IREST	16.6	23.7	30.8	μΑ	
	Reset τ Threshold Voltage H	VRESTH	7.7	-	-		VREST=1.5V
		VRESTL	-	-	0.4	V	VREST=1V

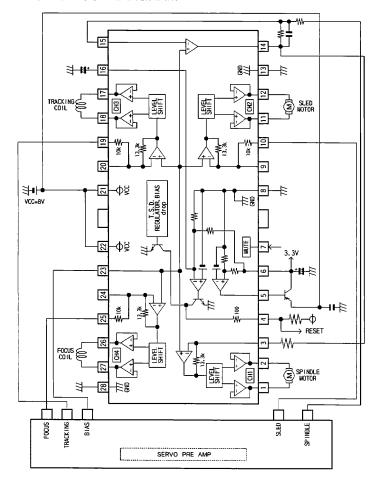
O OUTLINE DIMENSIONS, SYMBOLS



Rev.A

ROHM

O APPLICATION CIRCUIT DIAGRAM



CH1: SPINDLE CH2: SLED CH3: TRACKING CH4: FOCUS

T. S. D.: Thermal shutdown

Resistance unit: $[\Omega]$

O PIN NUMBERS, PIN NAMES

No.	Pin Name	Description	No.	Pin Name	Description
1	VO1(-)	Driver CH1 negative output	15	OPIN	Operational amplifier inverted input
2	VO1(+)	Driver CH1 positive output	16	RESETτ	Reset τ terminal
3	IN1	CH1 input terminal	17	VO3(-)	Driver CH3 negative output
4	RESET	Reset output	18	VO3(+)	Driver CH3 positive output
5	REGB	Regulator external Tr base connection terminal	19	IN3	CH3 input terminal
6	REGOUT	Regulator output	20	IN3'	CH3 input terminal for gain control
7	MUTE	Driver mute control terminal	21	VCC	Power supply input
8	GND	PREGND, REGGND	22	VCC	Power supply input
9	IN2'	CH2 input terminal for gain control	23	BIAS	Bias input
10	IN2	CH2 input terminal	24	IN4'	CH4 input terminal for gain control
11	VO2(+)	Driver CH2 positive output	25	IN4	CH4 input terminal
12	VO2(-)	Driver CH2 negative output	26	VO4(+)	Driver CH4 positive output
13	GND	CH2,3 POWGND	27	VO4(-)	Driver CH4 negative output
14	OPOUT	Operational amplifier output	28	GND	CH1,4 POWGND

Note: The positive or negative polarity of driver outputs is determined by the input polarity. When the signal H is applied to the input pin, the negative output pin outputs L and the positive output pin outputs H.

Rev.A



CAUTIONS ON USE

(1) Relationship between the mute function and the reset output

Function	Driver Mute Operation	Reset output		
Regulator voltage drop		'H'→'L'		
Bias voltage drop	ON in all cases	'H'→'L'		
Thermal shutdown		'H'→'L'		
Mute (pin 7)		Constant		

[Regulator Voltage Drop]

When the regulator voltage drops to 2.7V (typ.) or less, the reset output will become 'L' while the mute function will turn ON and, when the voltage recovers to 2.9V (typ.) or above, the reset output will become 'H' while the mute function will turn OFF.

[Bias Drop]

When the bias terminal (pin 23) voltage has dropped to 0.7V (typ.) or less, the mute function will turn ON while the reset output will become 'L'. Under conditions of normal use, it should be set to 1.2V or above

[Thermal Shutdown]

When the chip temperature has reached to 175°C (typ.) or above, the mute function will turn ON while the reset output will become 'L'. Ten the chip temperature has dropped to 150°C (typ.) or less, the mute function will turn OFF while the reset output will become 'H'. [Mute]

When the mute terminal (pin 7) voltage has set to open or dropped to 0.5V (typ.) or less, the mute function will turn ON while the reset output will not change.

(2) About reset τ terminal

Inserting a capacitor between the reset τ terminal (pin 16) and GND can set the delay time for the reset output.

The delay time t [sec] can be expressed by the following equation, where C[F] is a capacitance of the capacitor to be connected;

t=CV/I

When V=1.14[V], I=23.7[μ A] (typ.) and the capacitor with the capacitance of 4.7 μ F is connected, the delay time will become approximately 220msec.

- (3) Thermal shutdown (TSD), mute ON, bias terminal voltage drop, or regulator voltage drop will activate the mute function, where only the driver part can be muted. While muting, the voltage at the output terminal will equal to the internal bias voltage (approximately (VCC-VF) / 2).
- (4) The capacitor installed between the regulator output (pin 6) and GND also serves as an anti-oscillation capacitor and therefore, it is required to have high performance in the temperature characteristics.
- (5) While the regulator is not in use, the regulator output terminal (pin 6) must be shorted to VCC and the regulator external Tr base connection terminal (pin 5) must be open.
- (6) The radiating FIN must be connected to the external GND.
- (7) Short-circuits between output pin-VCC, output pin-GND, or output terminals (load short) must be avoided. Make sure that the ICs are installed on the board in proper directions.

 Mounting the ICs in improper directions may damage them or produce smoke.
- (8) About absolute maximum ratings

Exceeding the absolute maximum ratings, such as the applied voltage or the operating temperature range, may cause permanent device damage. As these cases cannot be limited to the broken short mode or the open mode, if a special mode where the absolute maximum ratings may be exceeded is assumed, it is recommended to take mechanical safety measures such as attaching fuses.

(9) About power supply lines

As a measure against the back current regenerated by a counter electromotive force of the motor, a capacitor to be used as a regenerated-current path can be installed between the power supply and GND and its capacitance value should be determined after careful check that any problems, for example, a leak capacitance of the electrolytic capacitor at low temperature, are not found in various characteristics.

(10) About GND potential

The electric potential of the GND terminal must be kept lowest in the circuitry at any operation states.



(11) About thermal design

With consideration of the power dissipation (Pd) under conditions of actual use, a thermal design provided with an enough margin should be done.

(12) About operations in a strong electric field

When used in a strong electric field, note that a malfunction may occur.

(13) ASO

When using this IC, the output Tr. must be set not to exceed the values specified in the absolute maximum ratings and ASO.

(14) Thermal shutdown circuit

This IC incorporates a thermal shutdown circuit (TSD circuit). When the chip temperature reaches the value shown below, the coil output to the motor will be set to open.

The thermal shutdown circuit is designed only to shut off the IC from a thermal runaway and not intended to protect or guarantee the entire IC functions.

Therefore, users cannot assume that the TSD circuit once activated can be used continuously in the subsequent operations.

TSD ON Temperature	Hysteresis Temperature
[°C] (typ.)	[°C] (typ.)
175	25

(15) About earth wiring patterns

When a small signal GND and a large current GND are provided, it is recommended that the large current GND pattern and the small signal GND pattern should be separated and grounded at a single point of the reference point of the set in order to prevent the voltage of the small signal GND from being affected by a voltage change caused by the resistance of the pattern wiring and the large current. Make sure that the GND wiring patterns of the external components will not change, too.

(16) This IC is a monolithic IC which has a P⁺ isolations and P substrate to isolate elements each other. This P layer and an N layer in each element form a PN junction to construct various parasitic elements. Due to the IC structure, the parasitic elements are inevitably created by the potential relationship. Activation of the parasitic elements can cause interference between circuits and may result in a malfunction or, consequently, a fatal damage. Therefore, make sure that the IC must not be used under conditions that may activate the parasitic elements, for example, applying the lower voltage than the ground level (GND, P substrate) to the input terminals.

Note that, while not applying the power supply voltage to the IC, any voltage must not be applied to the input terminals. In addition, do not applying the voltage to input terminals without applying the power supply voltage to the IC. Also while applying the power supply voltage, each input terminal must be the power supply voltage or less; or within the guaranteed values in the electric characteristics.

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ROHM

Appendix1-Rev1.1



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As of 18th. April 2005